

WLD-100-685 Red Laser Diode

685 nm, 100 mW

Features

- **Good FFP Performance**
- High Power
- High Efficiency
- 5.6 mm Package

Applications

- Excitation
- Bioanalytical
- Photolithography, Curing and others

Absolute Maximum Ratings

Parameter	Symbol	Condition	Rating	Unit
Light output power	Po	CW	105	mW
Reverse voltage (LD)	V_{RL}	-	2	V
Reverse voltage (PD)	V_{RD}	-	30	V
Case temperature	T _c	-	-10 to +70	°C
Storage temperature	Ts	-	-40 t0 +85	°C

Electrical and Optical Characteristics

Parameter	Symbol	Min	Тур.	Max	Unit	Condition
Threshold current	I_{th}	-	40	-	mA	-
Operating current	I _{op}	-	125	-	mA	
Operating voltage	V_{op}	-	2.35	-	V	
Peak wavelength	λ	-	685	-	nm	
Parallel divergence angle	911	-	9	ı	Degree	
Perpendicular divergence	θТ	-	14	-	Degree	P₀=100
angle						mW
Parallel FFP deviation angle	ΔθΙΙ	-3	0	3	Degree	
Perpendicular FFP deviation	$\Delta \theta T$	-3	0	3	Degree	
angle						
Monitor current	Im	0.1	0.2	0.5	mA	
Differential efficiency	η	-	1.17	_	mW/mA	P _o =5 - 100
						mW











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